

PSMN2R0-25YLD

N-channel 25 V, 2.09 m Ω , 179 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology

23 April 2021

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package. NextPowerS3 portfolio utilising Nexperia's unique "SchottkyPlus" technology delivers high efficiency, low spiking performance usually associated with MOSFETS with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- 100% Avalanche tested at I_(AS) = 118 A
- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- · Superfast switching with soft-recovery
- · Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 µA leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Power SO8 package; no glue, no wire bonds, qualified to 175 °C
- Wave solderable; exposed leads for optimal visual solder inspection

3. Applications

- On-board DC:DC solutions for server and telecommunications
- · Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- · Brushed and brushless motor control

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	25	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	179	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	115	W
Tj	junction temperature			-55	-	175	°C
Static characte	eristics		,				
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	2.41	2.91	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	1.82	2.09	mΩ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Dynamic chara	Dynamic characteristics								
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13		-	34.1	-	nC		
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	15.7	-	nC		
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V		-	15.2	-	nC		
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	3.6	-	nC		
Source-drain diode									
S	softness factor	I_S = 25 A; dI_S/dt = -100 A/s; V_{GS} = 0 V; V_{DS} = 12 V; Fig. 16		-	1	-			

^{[1] 179}A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	S	source	mb	D		
2	S	source	<u> </u>			
3	S	source	d	G—(F)		
4	G	gate	1 (/	0 0 0 0	0 0 0 0	mbb076 S
mb	D mounting base; conne to drain	mounting base; connected to drain	1 2 3 4 LFPAK56; Power- SO8 (SOT669)			

6. Ordering information

Table 3. Ordering information

Table 5. Ordering information									
	Type number	Package							
		Name	Description	Version					
	PSMN2R0-25YLD	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669					

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN2R0-25YLD	2D025L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	25	V
V_{DGR}	drain-gate voltage	25 °C ≤ Tj ≤ 175 °C; RGS = 20 kΩ		-	25	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	115	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	179	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	127	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	722	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
V _{ESD}	electrostatic discharge voltage	HBM (JEDEC)		600	-	V
Source-drain	diode		'	<u> </u>		
I _S	source current	T _{mb} = 25 °C		-	95	А
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	722	Α
Avalanche ru	ggedness			'	'	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 25 A; $V_{sup} \le 25$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 1.01 ms		-	410	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 25 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R_{GS} = 50 Ω	[2]	-	118	A

^{[1] 179}A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

^[2] Protected by 100% test

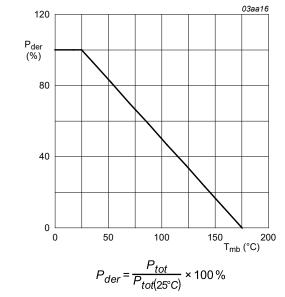
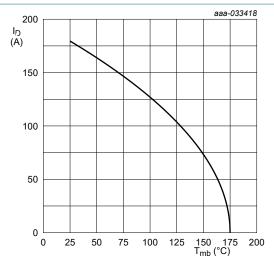


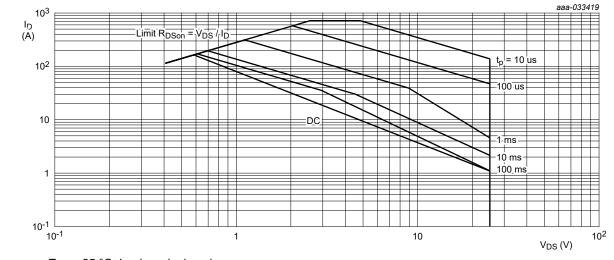
Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$

(1) 179A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	1.09	1.31	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	50	-	K/W
junction to ambient	Fig. 6	-	125	-	K/W	

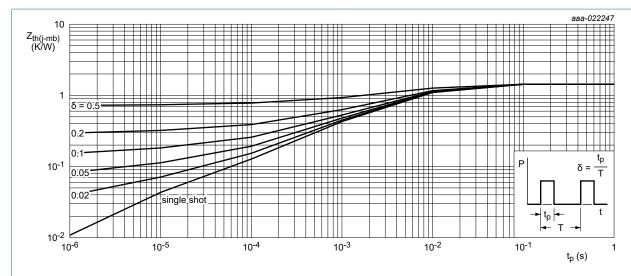


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

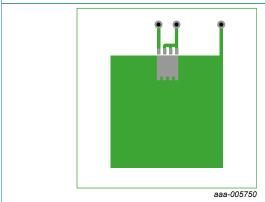


Fig. 5. PCB layout for thermal resistance junction to ambient 1" square pad; FR4 Board; 2oz copper

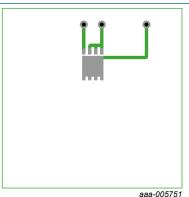


Fig. 6. PCB layout for thermal resistance junction to ambient minimum footprint; FR4 Board; 2oz copper

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static charac	teristics		'	'			
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C		25	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$		22.5	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$		1.2	1.68	2.2	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 175 °C		-	-4.5	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C		-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C		-	3.9	-	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C		-	-	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C		-	-	100	nA

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{DSon}	_	$V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	2.41	2.91	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 175 °C; Fig. 10; Fig. 11		-	-	4.95	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10		-	1.82	2.09	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11		-	-	3.52	mΩ
R_G	gate resistance	f = 1 MHz		-	0.849	-	Ω
Dynamic ch	aracteristics						
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13		-	34.1	-	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	15.7	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V		-	15.2	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		-	6.4	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		-	3.8	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	2.6	-	nC
Q _{GD}	gate-drain charge			-	3.6	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.8	-	V
C _{iss}	input capacitance	V _{DS} = 12 V; V _{GS} = 0 V; f = 1 MHz;		-	2485	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	1142	-	pF
C _{rss}	reverse transfer capacitance			-	152	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 12 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V;		-	15.7	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	18.7	-	ns
t _{d(off)}	turn-off delay time			-	18.7	-	ns
t _f	fall time			-	12.4	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 12 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	23	-	nC
Source-drai	in diode						
V _{SD}	source-drain voltage	I _S = 20 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	8.0	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}$; $dI_S/dt = -100 \text{ A/s}$; $V_{GS} = 0 \text{ V}$;		-	26	-	ns
Q _r	recovered charge	V _{DS} = 12 V; <u>Fig. 16</u>	[1]	-	16.8	-	nC
t _a	reverse recovery rise time			-	13	-	ns
t _b	reverse recovery fall time			-	13	-	ns
S	softness factor			-	1	-	

^[1] Includes capacitive recovery

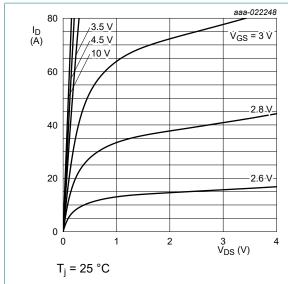


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

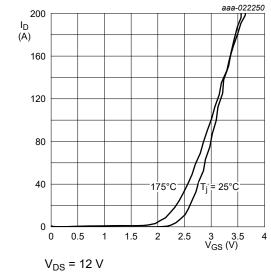


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

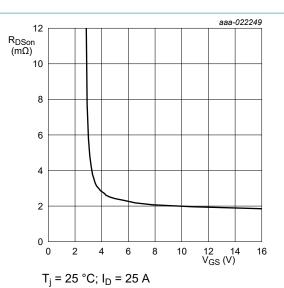


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

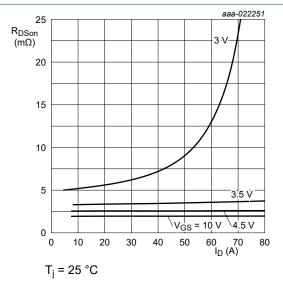


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

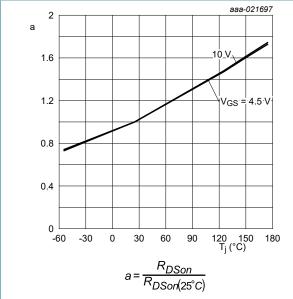


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

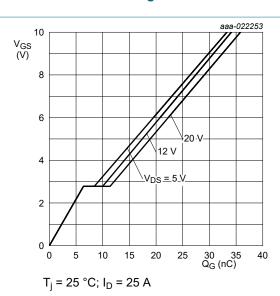


Fig. 12. Gate-source voltage as a function of gate charge; typical values

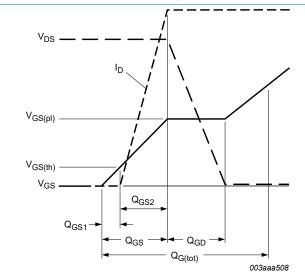


Fig. 13. Gate charge waveform definitions

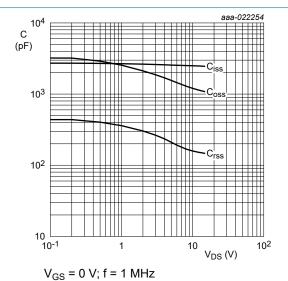


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

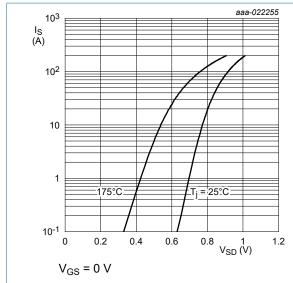


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

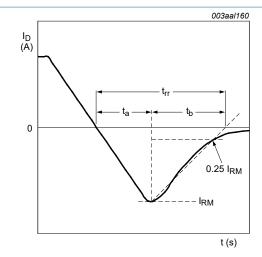
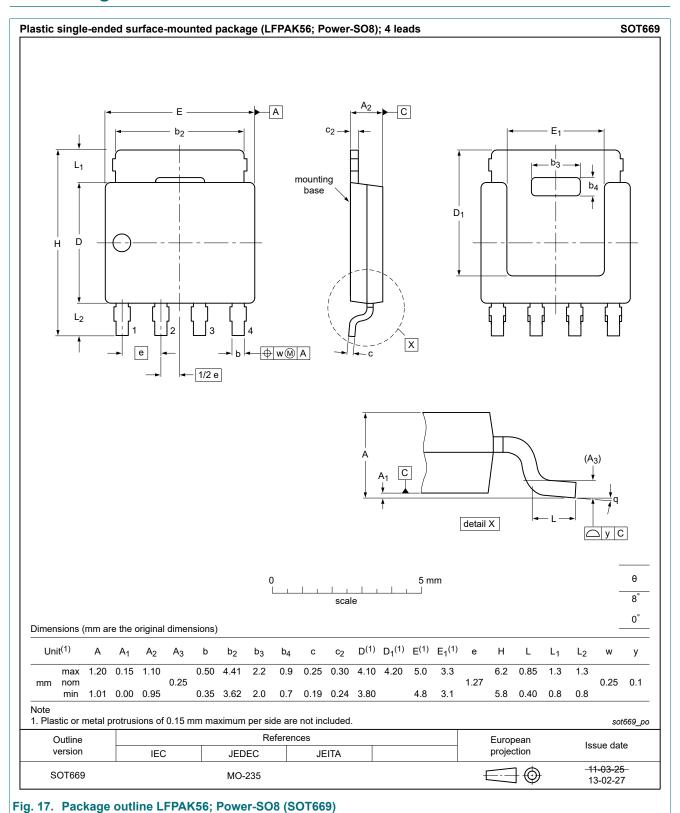
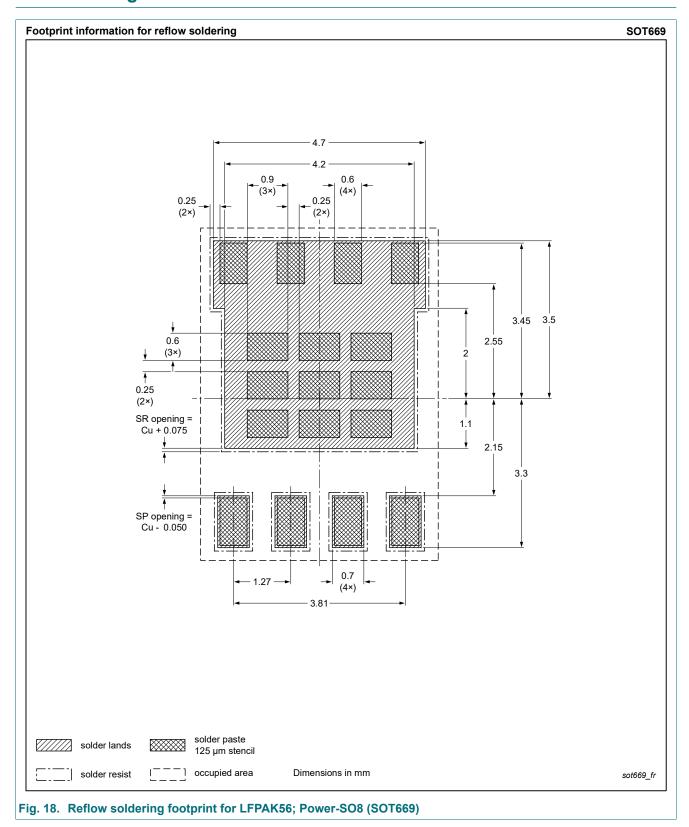


Fig. 16. Reverse recovery timing definition

11. Package outline



12. Soldering



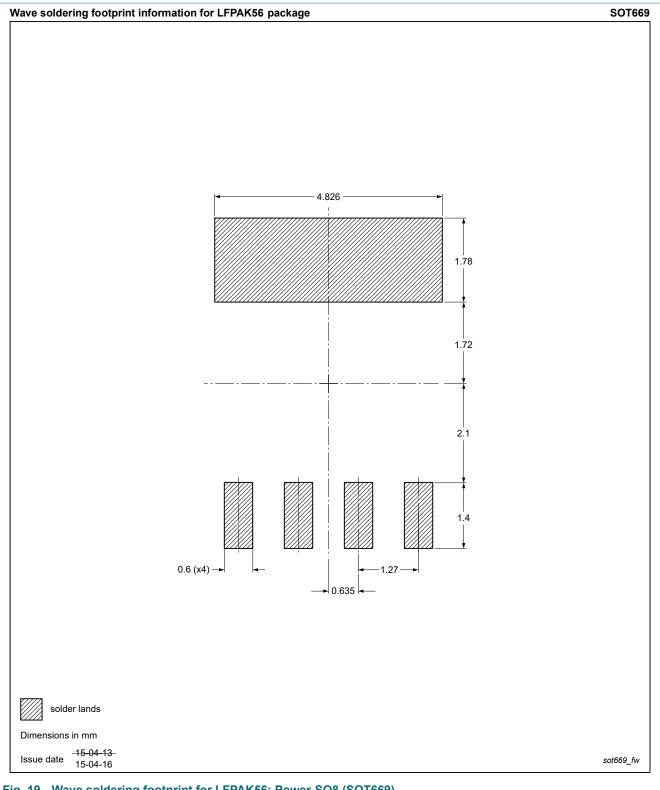


Fig. 19. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
	Thermal characteristics	
10.	. Characteristics	5
11.	Package outline	10
12.	. Soldering	11
13.	Legal information	13

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